

MICRO-429: Metrology Practicals

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Introduction

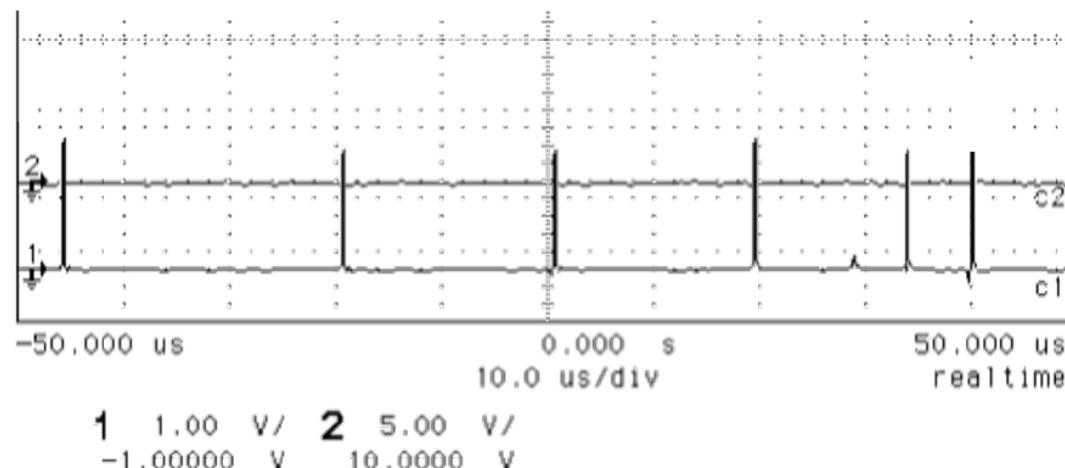
- 6 weeks @4-5h/week (+1x Intro +1x preparation), 3 credits, Tue 13-17/18
 - There will not be a Zoom link, due to the experimental nature of the course:
 - There will not be “Office hours”. Please make sure you ask all your questions during the practical.
- This course is intended as the experimental addition to MICRO-428 (Metrology).
- The students will have a chance to practice the theoretical concepts they learnt there.
- They will also learn good practices during measurements, while designing the experiments required for specific measurements.
- The course will propose 6 experiments in time slots of 4-5 hours in the second part of the semester.
- Learning outcome: become familiar with the measurement techniques and theory learnt in MICRO-428. The students will have the opportunity to work with real instruments and **keep a lab notebook**.

Topics

- Quantum metrology
 - Single-photon experiments
 - Correlated / uncorrelated noise
 - Time-resolved experiments
- AFM
- SEM

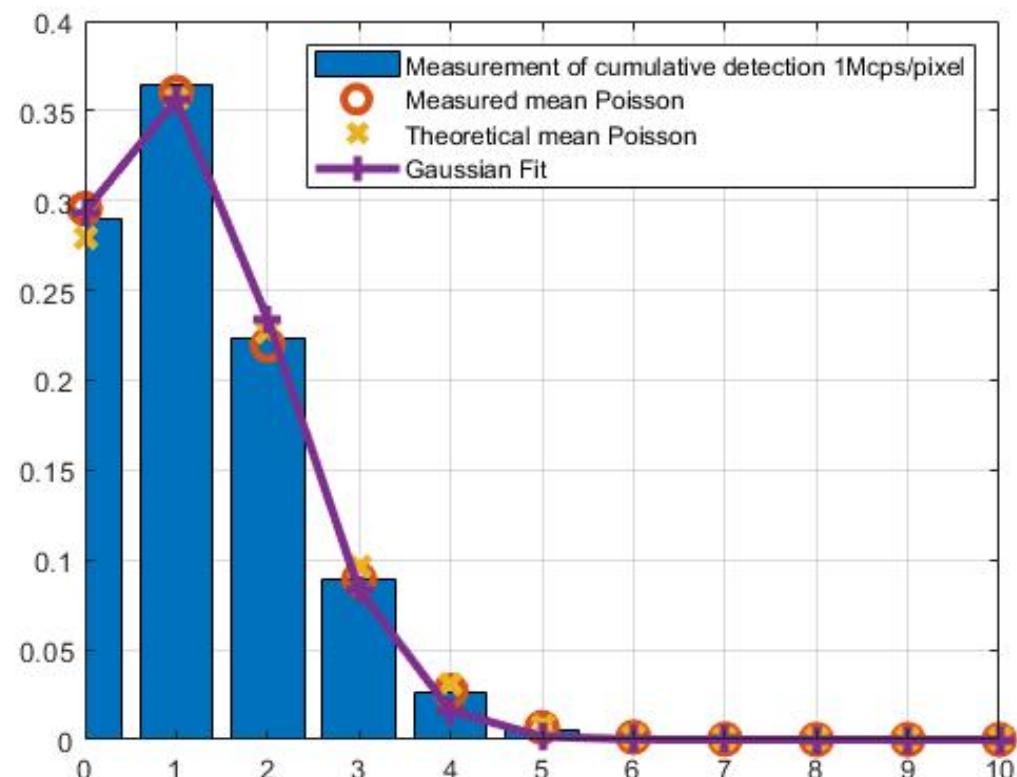
Content/1

- [T1] Dark count rate (DCR) and afterpulsing statistics in photon-counting devices
 - Understanding single-photon avalanche diodes (SPADs) & photon counting
 - DCR vs. excess bias voltage
 - Inter-arrival statistics, dead time, and afterpulsing
 - (Temperature dependency)

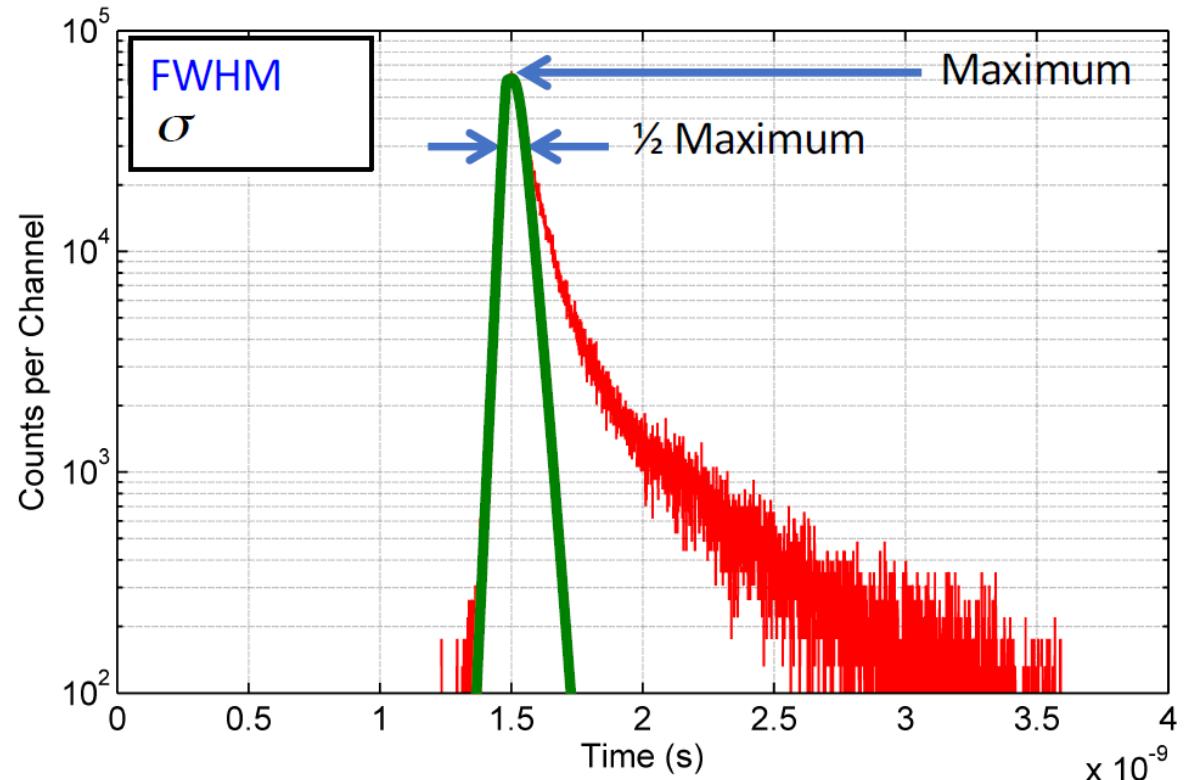


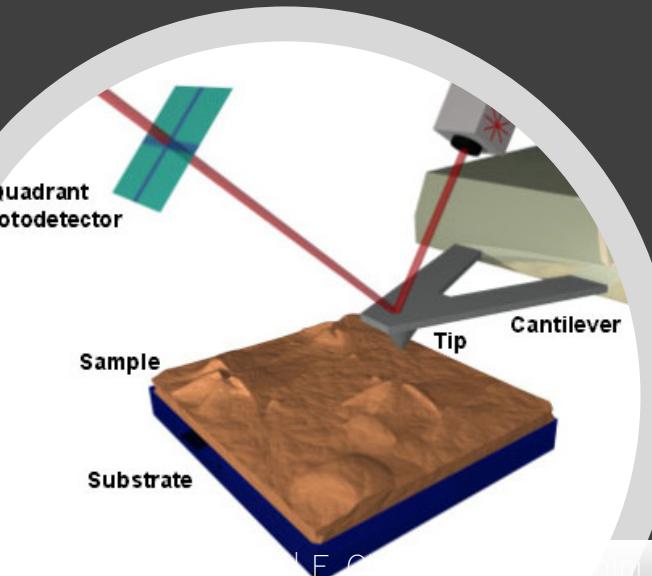
- [T2] Sensitivity in photon-counting devices

- Photon detection probability (PDP) and efficiency (PDE)
- Poisson nature of photons, “hand diagram”
- Photo-response non-uniformity (PRNU)



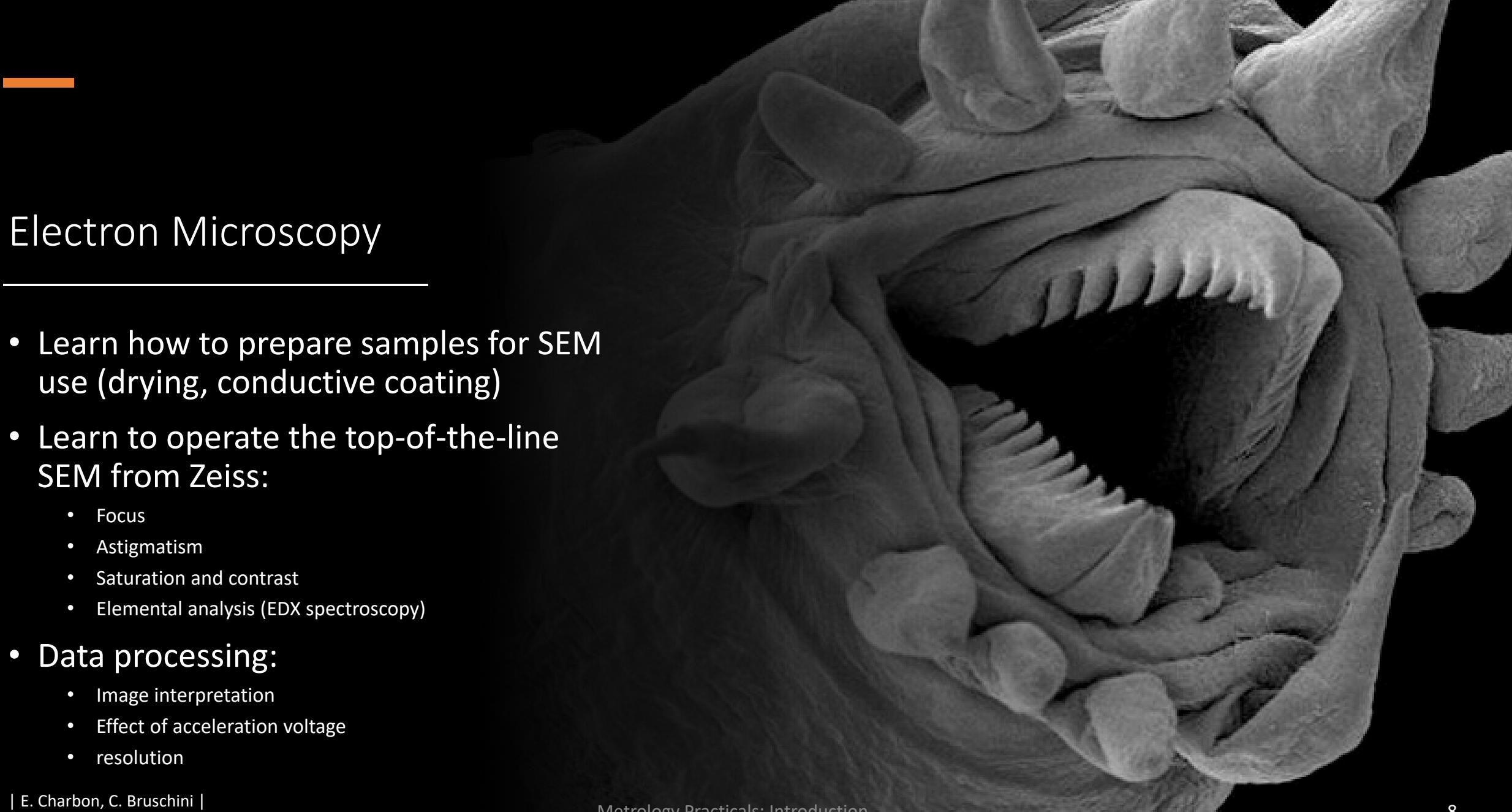
- [T3] Timing jitter measurements in single-photon detectors
 - Time-correlated single-photon counting (TCSPC)
 - Single-photon timing resolution (SPTR)
 - Pile-up effect





AFM a Versatile Tool for Nanoscale Measurements

- Things you will learn:
 - Make surface topography images with sub nanometer resolution
 - Nanoscale imaging of E.coli.
 - Extract tendons from rat tails, image microfibrils of collagen and measure the characteristic D-banding structure of collagen fibrils
 - How to process and analyze AFM data



Electron Microscopy

- Learn how to prepare samples for SEM use (drying, conductive coating)
- Learn to operate the top-of-the-line SEM from Zeiss:
 - Focus
 - Astigmatism
 - Saturation and contrast
 - Elemental analysis (EDX spectroscopy)
- Data processing:
 - Image interpretation
 - Effect of acceleration voltage
 - resolution



Imaging of the eye of a fruit-fly

Zeiss crossbeam 550L



Course Structure

- W1 – kickoff class (today): explain exercises, form groups, intro to lab notebook keeping, reminder intro to Matlab, reminder laser safety training
- W2: 2024 version of hand-outs of lab material available for ALL modules (T1-T6)
- W6 (Mar. 24) – W7 (Mar. 31): revised hand-outs as needed and preparation class (TBC)
- W8 (Apr. 07) – W13 (May 19) (every W): N groups of 2 students will go through all 6 modules (T1-T6)
- Students will get a grade on each module (1 point max per module). The final grade is going to be the sum of the individual grades.
- **Quantum Metrology (photonics): each group will need to prepare Matlab code pieces in advance, using practice data where appropriate. Typical tasks: data input, understand data structure, fitting, plotting.**
- **Nanoscale Metrology: each group will have an entry quiz (multiple choice questions), so as to verify that they understood the material beforehand, while their lab notebook will be examined at the end of each module.**

If they fail the Matlab code preparation or quiz, they will still be able to go through the module, but will get only 0.5-0.75 points in total if they succeed.

Group Study

Date	Apr. 07	Apr. 14	Apr. 28	May 5	May 12	May 19
Week	W8	W9	W10	W11	W12	W13
G1	T1	T2	T3	T4	T5	T6
G2	T2	T3	T1	T5	T6	T4
G3	T3	T1	T2	T6	T4	T5
G4	T4	T5	T6	T1	T2	T3
G5	T5	T6	T4	T2	T3	T1
G6	T6	T4	T5	T3	T1	T2

Example – G1-G6 = Groups, T1 – T6 = Modules, W7 – W12 = Weeks

Example – Task 1

Dark count rate (DCR) and afterpulsing statistics in photon-counting devices

Objective:

- Understanding single-photon avalanche diodes (SPADs) & photon counting
- DCR vs. excess bias voltage
- Inter-arrival statistics, dead time, and afterpulsing
- (Temperature dependency)

Reading:

- Read reference [1] for general understanding of SPAD technology
- Read week 8 lecture notes – Introduction to single-photon detection

Setup:

- 1 Voltage supply
- 1 SPAD23™ detection unit
- (1 oscilloscope)

Example – Task 1

Dark count rate (DCR) and afterpulsing statistics in photon-counting devices

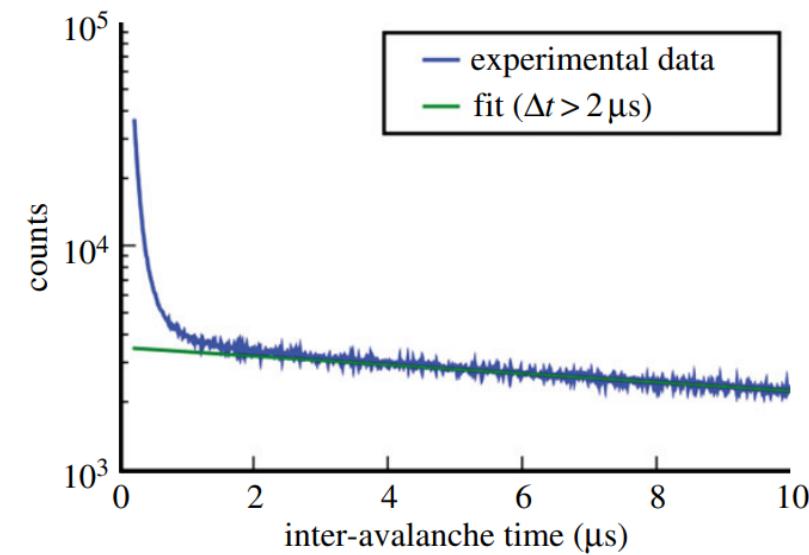
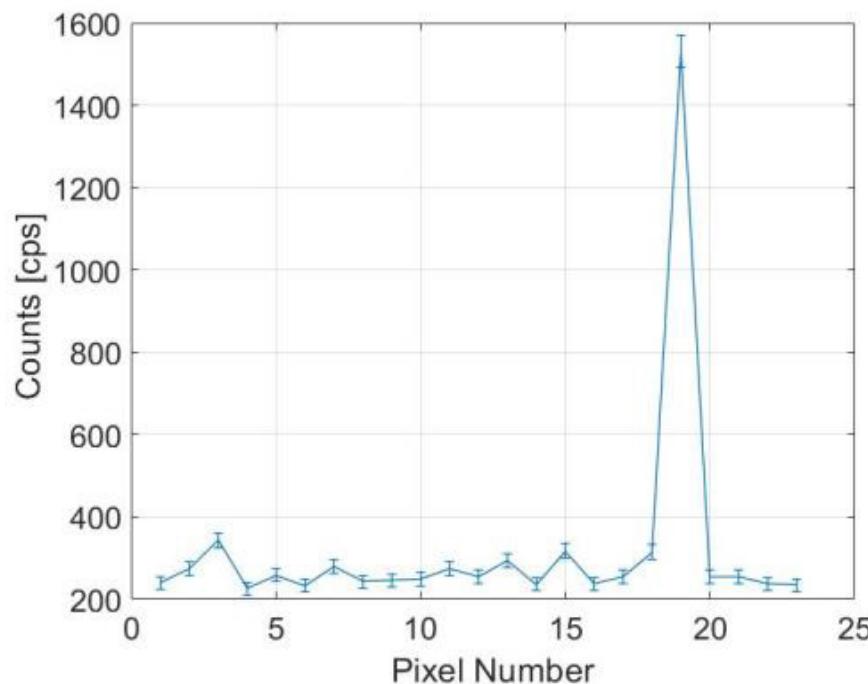
Methodology:

- Connect the SPADs to the power and observe the pulses generated by the device when exposed to light.
- Test the built-in oscilloscope and compare the curves with the external oscilloscope.
- Use the counter option and measure DCR vs. Excess bias.
- Repeat with the other SPADs at one configuration ($V_{EX}=3V$) and compute median and mean DCR. Which one is higher? Why?
- Set up the detection unit to extract inter-arrival times.
- Construct the histogram and compute dead time and afterpulsing with $V_{EX}=3V$.
- Document your findings on the Lab Notebook along the way.

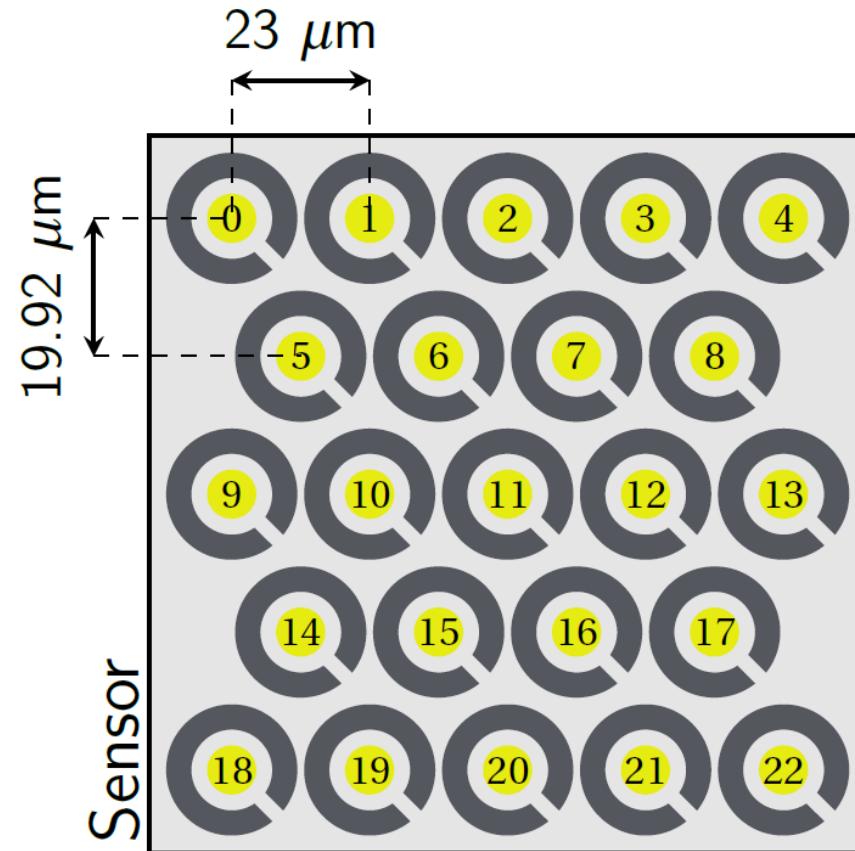
[1] E. Charbon, “Single-photon imaging in complementary metal oxide semiconductor processes”, Phil. Trans. Royal Society, 28 March 2014. DOI: 10.1098/rsta.2013.0100.

Example – Task 1

Dark count rate (DCR) and afterpulsing statistics in photon-counting devices



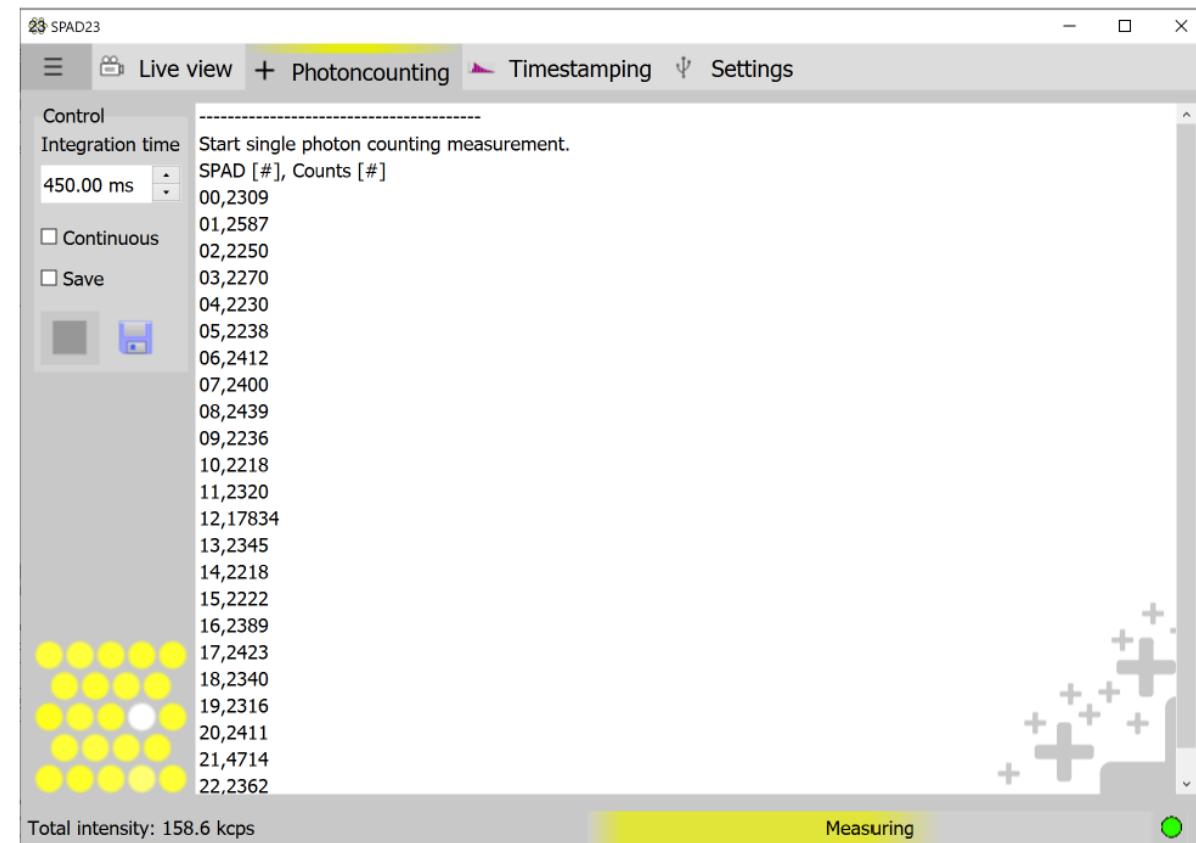
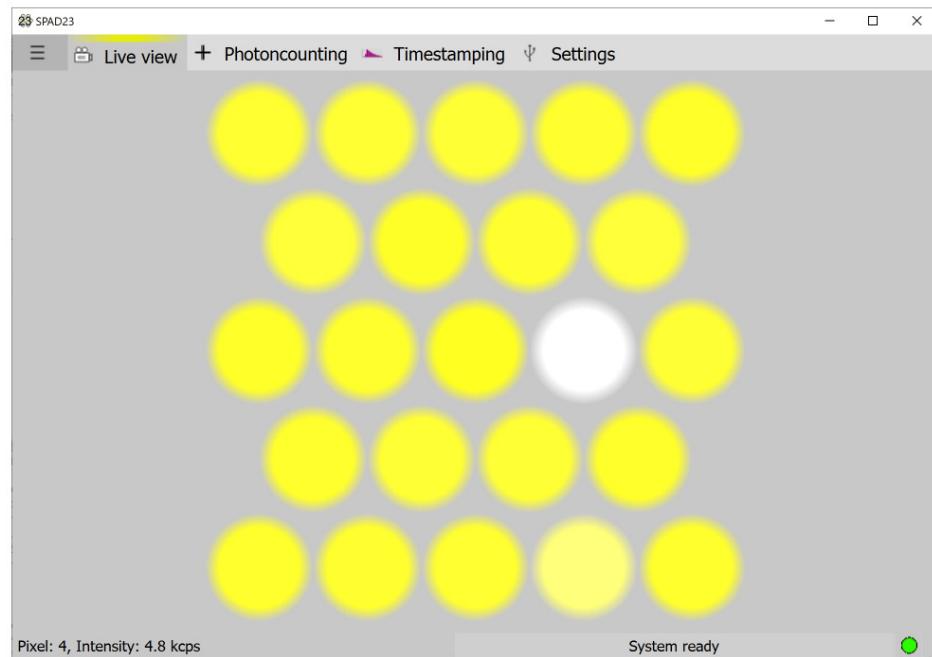
Key Instrumentation – SPAD23 single-photon sensor



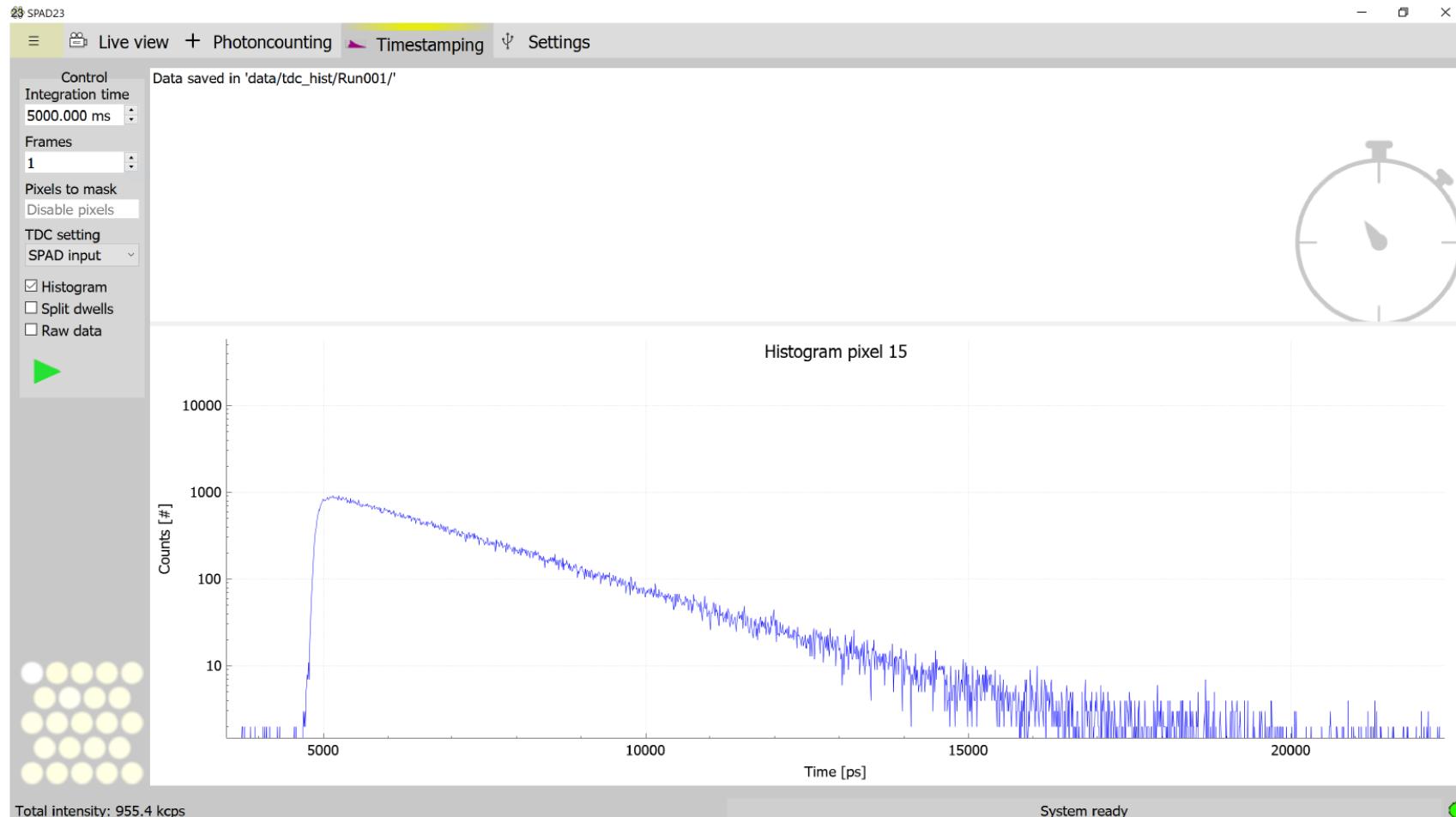
pi  imaging

SPAD23: photon-counting

Photoncounting



SPAD23: time-stamping



Programming examples

Below follow some programming examples for Matlab/Octave/Python. The first one measures the count rates at different voltages. The second one measures the count rates versus the integration time. The third one performs a timestamping measurement when the TDC is enabled. The last one shows the capability of real-time streaming of photon timestamps.

Code example 1: Matlab – Count rate versus operating voltage

```
1 % open the device on the localhost, port 9999
2 t = tcpip('localhost', 9999);
3 fopen(t);
4
5 % read the server response
6 bytesav      = get(t, 'bytesavailable');
7 msg          = fread(t, bytesav);
8 msgstr       = convertCharsToStrings(msg)
9
10 % set the voltage sweep for VOP that we want to execute from 26 to 32 V
11 voltages     = 26:0.5:31.5;
12 counts       = zeros(size(voltages));
13 for i = 1:length(voltages)
14
```

Other Key Instrumentation – ps Laser Diode

